

# RJL5012DPP-M0

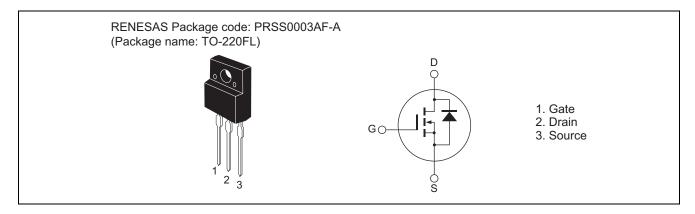
# Silicon N Channel MOS FET High Speed Power Switching

R07DS0419EJ0100 Rev.1.00 May 26, 2011

#### **Features**

- Built-in fast recovery diode
- Low on-resistance  $R_{DS(on)} = 0.56~\Omega~typ.~(at~I_D=6~A,~V_{GS}=10~V,~Ta=25^{\circ}C)$
- Low leakage current
- High speed switching

## **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	500	V
Gate to source voltage	V <sub>GSS</sub>	±30	V
Drain current	I <sub>D</sub> Note4	12	Α
Drain peak current	I <sub>D (pulse)</sub> Note1	36	Α
Body-drain diode reverse drain current	I <sub>DR</sub>	12	Α
Body-drain diode reverse drain peak current	I <sub>DR (pulse)</sub> Note1	36	Α
Avalanche current	I <sub>AP</sub> Note3	3	Α
Avalanche energy	E <sub>AR</sub> Note3	0.5	mJ
Channel dissipation	Pch Note2	30	W
Channel to case thermal impedance	θch-c	4.17	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

- 2. Value at Tc = 25°C
- 3. STch =  $25^{\circ}$ C, Tch  $\leq 150^{\circ}$ C
- 4. Limited by maximum safe operation area

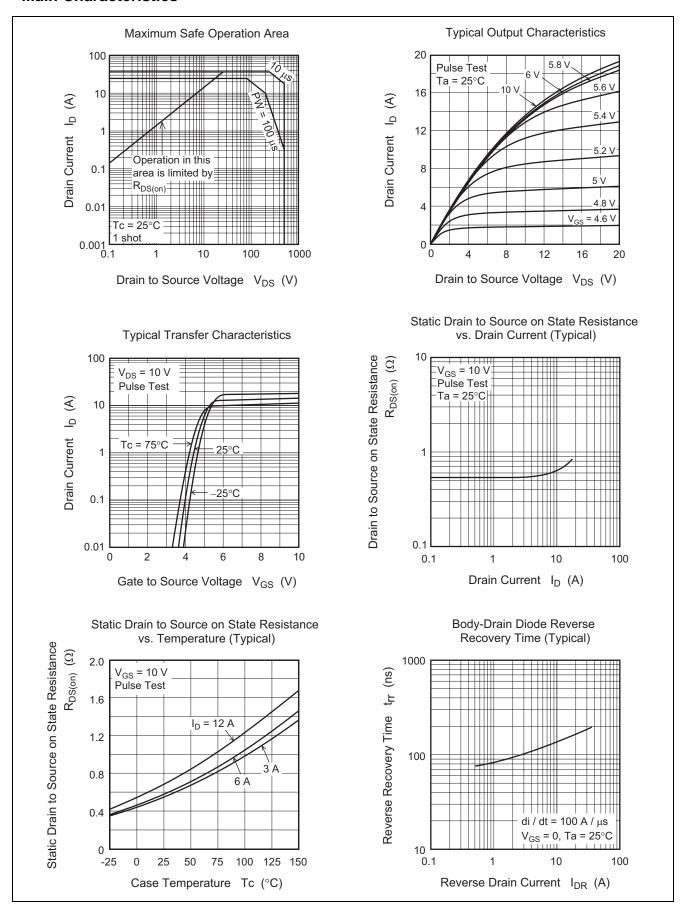
## **Electrical Characteristics**

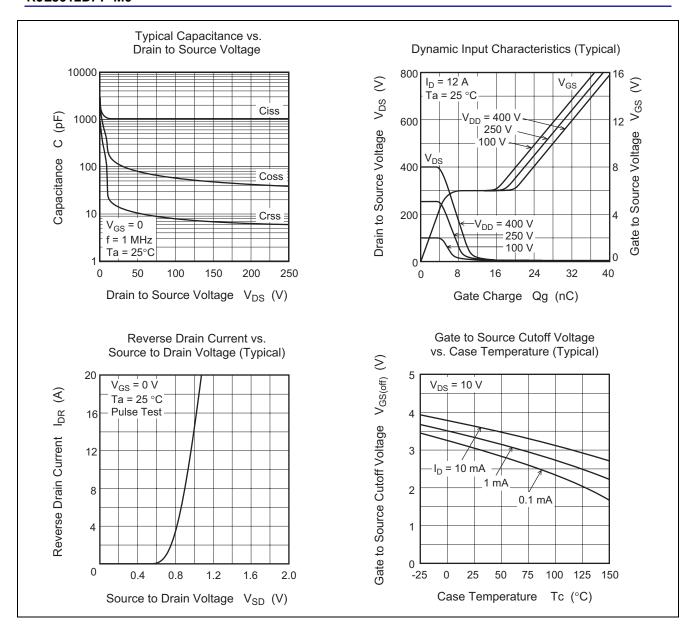
 $(Ta = 25^{\circ}C)$ 

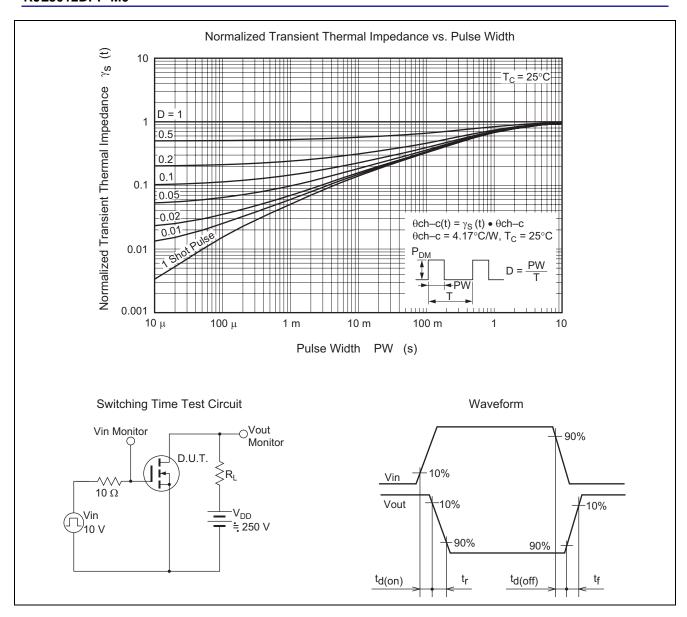
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	500	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	10	μΑ	$V_{DS} = 500 \text{ V}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	2.0	_	4.0	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R <sub>DS(on)</sub>	_	0.56	0.70	Ω	$I_D = 6 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note5}}$
resistance						
Input capacitance	Ciss	_	1050	_	pF	V <sub>DS</sub> = 25 V
Output capacitance	Coss	_	115	_	pF	V <sub>GS</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	14	_	pF	
Turn-on delay time	t <sub>d(on)</sub>	_	27	_	ns	I <sub>D</sub> = 6 A
Rise time	t <sub>r</sub>	_	22	_	ns	$ \begin{array}{c} V_{GS} = 10 \text{ V} \\ R_L = 41.7 \ \Omega \\ Rg = 10 \ \Omega \end{array} $
Turn-off delay time	t <sub>d(off)</sub>	_	78	_	ns	
Fall time	t <sub>f</sub>	_	15	_	ns	
Total gate charge	Qg	_	27.8	_	nC	V <sub>DD</sub> = 400 V
Gate to source charge	Qgs	_	4.9	_	nC	V <sub>GS</sub> = 10 V I <sub>D</sub> = 12 A
Gate to drain charge	Qgd	_	14.4	_	nC	
Body-drain diode forward voltage	$V_{DF}$	_	0.96	1.60	V	$I_F = 12 \text{ A}, V_{GS} = 0^{\text{Note5}}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	140	_	ns	I <sub>F</sub> = 12 A, V <sub>GS</sub> = 0
						$di_F/dt = 100 A/\mu s$

Notes: 5. Pulse test

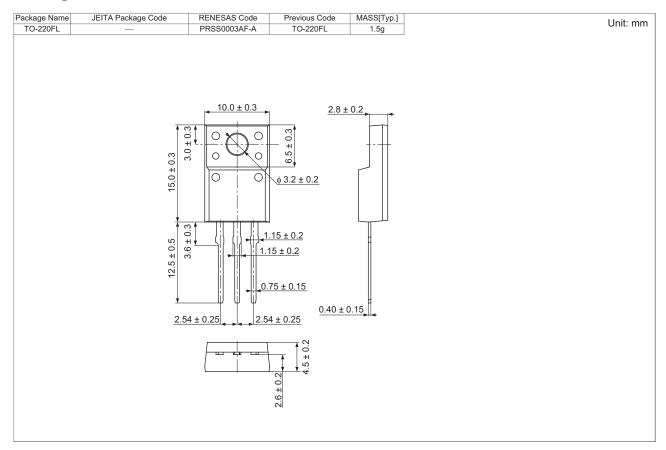
### **Main Characteristics**







## **Package Dimensions**



## **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJL5012DPP-M0-T2	600 pcs	Box (Tube)

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